

## 50 $\Omega$ / 50 $\Omega$ Low Noise Amplifier

PRELIMINARY DATA

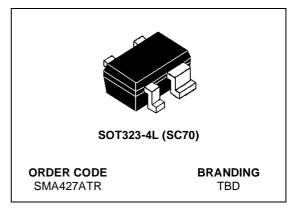
- CASCADABLE 50 ohm-GAIN BLOCK
- UNCONDITIONALLY STABLE
- GAIN  $|S_{21}|^2 = 17$  dB at 1.8 GHz
- IP3out = +7.4 dBm at 1.575 GHz (V<sub>D</sub> = 3 V, I<sub>D</sub> = 9.5 mA)
- NOISE FIGURE NF = 2.2 dB at 1.8 GHz
- TYPICAL DEVICE VOLTAGE VD = 2 V to 5 V
- ULTRA MINIATURE SOT323-4L PACKAGE (LEAD FREE)

#### **APPLICATIONS**

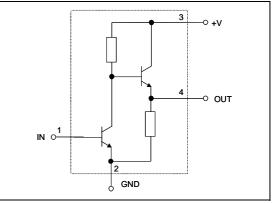
LNA FOR 1-2 GHz APPLICATIONS (GPS, Cellular..)

#### DESCRIPTION

SMA427A is a product of the SMA Family (Silicon MMIC Amplifiers). Housed in the ultra miniature 4-lead SC-70 (SOT323-4L LEAD FREE) surface mount plastic package, it embeds the state of the art Silicon ST technology. The amplifier application shows excellent RF performance using only two external component in the 1000-2000MHz frequency range.



#### **BLOCK DIAGRAM**



#### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
VD	Device Voltage	6	V
Ι <sub>D</sub>	Device Current	27	mA
P <sub>tot</sub>	Total dissipation, $T_s = 120 \ ^{\circ}C$	TBD	mW
P <sub>RFin</sub>	RF Input Power	-10	dBm
T <sub>amb</sub>	Ambient Temperature	-65 to +150	°C
T <sub>stg</sub>	Storage temperature	-65 to +150	°C
Тј	Max. operating junction temperature	150 °C	

#### THERMAL RESISTANCE

R <sub>thjs</sub> Thermal Resistance Junction soldering point	TBD	°C/W
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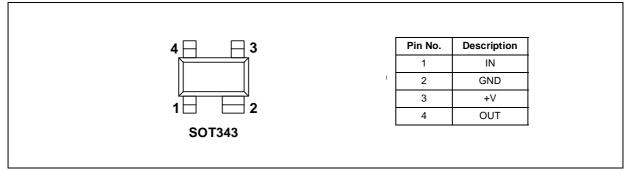
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## **ELECTRICAL CHARACTERISTICS**

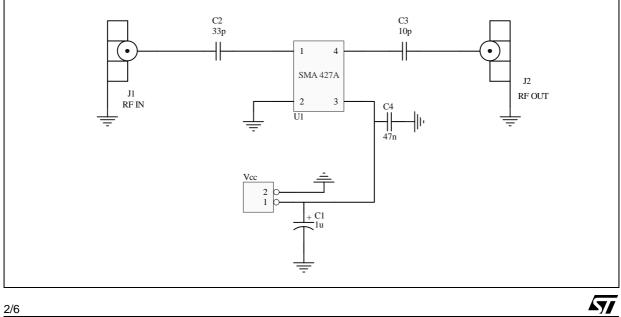
 $(Ta = +25^{\circ}C, VD = 3V, Zo = 50\Omega, tested in circuit shown in Appl.1, unless otherwise specified)$ 

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
ld	Supply Current			9.5		mA
S21  <sup>2</sup>	Insertion power gain	f = 1 GHz f = 1.575 GHz f = 1.8 GHz		22 18 17		dB
S12	Reverse Isolation	f = 1 GHz f = 1.575 GHz f = 1.8 GHz		27 25 20		dB
NF	Noise Figure	f = 1 GHz f = 1.575 GHz f = 1.8 GHz		1.8 2 2.2		dB
IP <sub>3out</sub>	Intercept point at output	f = 1.575 GHz		7.4		dBm
RLin	Input Return Loss	f = 1 GHz f = 1.575 GHz f = 1.8 GHz		>12 >12 >12 >12		dB
RLout	Output Return Loss	f = 1 GHz f = 1.575 GHz f = 1.8 GHz		>12 >12 >12 >12		dB

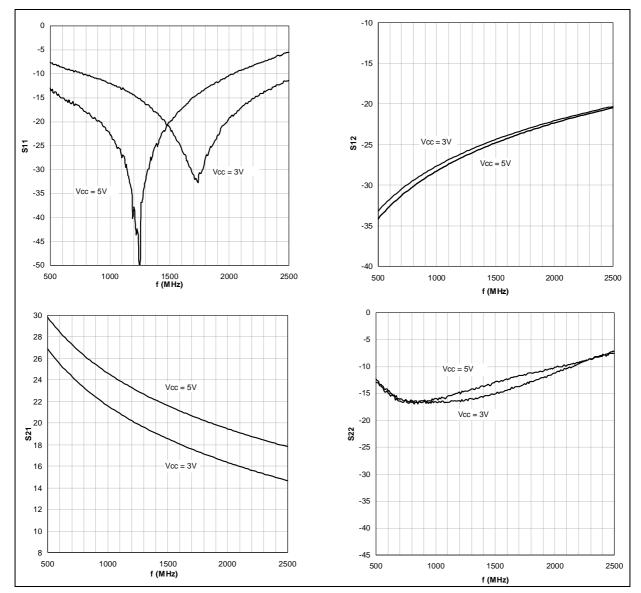
#### **PIN CONNECTION**



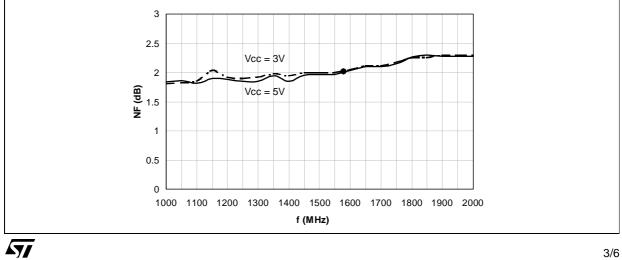
## **Typical configuration**



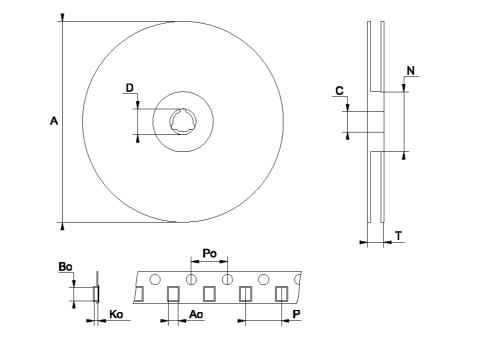
#### **S-Parameters**



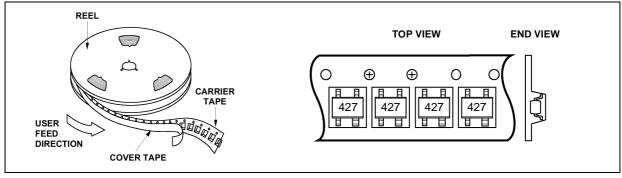
## Noise Figure vs. Frequency



TAPE & REEL DIMENSIONS					
	mm				
	MIN.	TYP.	MAX		
А	178.5	179	179.5		
С	12.8	13.0	13.5		
D	20.2				
Ν	54.5	55	55.5		
Т			14.4		
Ao		2.25			
Во		2.7			
Ko		1.2			
Po	3.8 (cumulative 10 Po)	4.0	4.2 (cumulative 10 Po)		
Р		4.0			

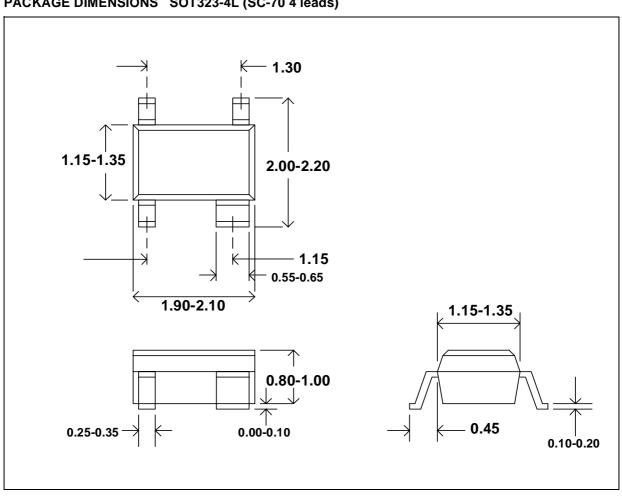


## **DEVICE ORIENTATION**



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PACKAGE DIMENSIONS SOT323-4L (SC-70 4 leads)

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